L Number	Hits	Search Text	DB	Time stamp
1	2	("20020072133").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/18 12:00
2	2	("4567364").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/18 12:19
3	2	("5479535").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/18 12:36
4	2	("5887080").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/18 12:42
5	2	("5479535").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/18 14:00
6	2	("4567364").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/18 12:45
7	2	("6785873").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/18 14:04
8	2	("6801650").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/18 14:20
9	2	("6757645").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/18 14:25
10	2	("6651225").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/18 14:28
11	2	("6583414").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/18 14:32
12	2	("6578188").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/18 14:34
13	2	("6542830").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/18 14:40
14	2	("6531697").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/18 14:41
15	7	("6476913").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/18 14:48
16	1	("5777327").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/18 14:48
-	13	HSG and OCS	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/18 11:59

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–	2892	HSG or (grow near4 hemispherical near4 grains)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/12 12:47
–	15	(HSG or (grow near4 hemispherical near4 grains)) and ((grow$3 near5 (degree or size or volume or dimension)) same (wafer or semiconductor))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/13 11:43
–	2	("20020106127").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/12 16:07
–	7	(HSG or (grow near4 hemispherical near4 grains)) and ((grow$3 near5 (degree or size or volume or dimension)) same (wafer or semiconductor)) and (image or pixel or picture)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/13 17:14
–	621	(HSG or (grow$3 near4 hemispherical near4 grains) or ((grain or size or degree or volume or dimension) near5 grow$3)) and ((compar$3 or analy$4) same image same pixel)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/13 17:28
–	2007	382/145,194.ccls. 438/207,208,231,232.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/13 17:18
–	8	((HSG or (grow$3 near4 hemispherical near4 grains) or ((grain or size or degree or volume or dimension) near5 grow$3)) and ((compar$3 or analy$4) same image same pixel)) and (382/145,194.ccls. 438/207,208,231,232.ccls.)	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/13 17:18
–	615	(HSG or (grow$3 near4 hemispherical near4 grains) or ((grain or size or degree or volume or dimension) near5 grow$3)) and ((compar$3 or analy$4) same (image or pixel or picture) same (predetermine or threshold or limit))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/13 17:30
–	136	382/$.ccls. and ((HSG or (grow$3 near4 hemispherical near4 grains) or ((grain or size or degree or volume or dimension) near5 grow$3)) and ((compar$3 or analy$4) same (image or pixel or picture) same (predetermine or threshold or limit)))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/13 17:30
–	190	(semiconductor or wafer) and (HSG or (grow$3 near4 hemispherical near4 grains) or ((grain or size or degree or volume or dimension) near5 grow$3)) and ((compar$3 or analy$4) same (image or pixel or picture) same (predetermine or threshold or limit))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/13 17:51
–	9	382/$.ccls. and ((semiconductor or wafer) and (HSG or (grow$3 near4 hemispherical near4 grains) or ((grain or size or degree or volume or dimension) near5 grow$3)) and ((compar$3 or analy$4) same (image or pixel or picture) same (predetermine or threshold or limit)))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/13 17:41
–	13	438/$.ccls. and ((semiconductor or wafer) and (HSG or (grow$3 near4 hemispherical near4 grains) or ((grain or size or degree or volume or dimension) near5 grow$3)) and ((compar$3 or analy$4) same (image or pixel or picture) same (predetermine or threshold or limit)))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/13 17:41

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–	27	(semiconductor or wafer) and (HSG or (grow$3 near4 hemispherical near4 grains) or ((grain or size or degree or volume or dimension) near5 grow$3)) and ((compar$3 or analy$4) near7 (image or pixel or picture) near7 (predetermine or threshold or limit))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/14 14:26
–	2	("6778685").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/14 12:53
–	28	(semiconductor or wafer) and (HSG or (grow$3 near4 hemispherical near4 grains) or ((grain or size or degree or volume or dimension or depth or height) near5 grow$3)) and ((compar$3 or analy$4) near7 (image or pixel or picture) near7 (predetermine or threshold or limit))	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/14 14:30
–	2	("6785873").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/10/14 14:31